

BYV32-200

Switch-mode Power Rectifier

Features and Benefits

- Low Forward Voltage
- Low Power Loss/High Efficiency
- High Surge Capacity
- 175°C Operating Junction Temperature
- 16 A Total (8 A Per Diode Leg)
- These Devices are Pb-Free and are RoHS Compliant*

Applications

- Power Supply – Output Rectification
- Power Management
- Instrumentation

Mechanical Characteristics

- Case: Epoxy, Molded
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes:
260°C Max. for 10 Seconds
- ESD Rating: Human Body Model 3B
Machine Model C

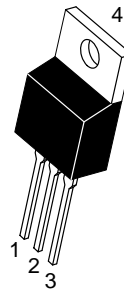
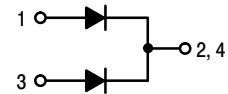


ON Semiconductor®

www.onsemi.com

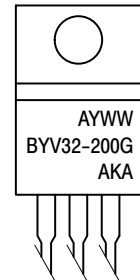
ULTRAFAST RECTIFIER
16 AMPERES, 200 VOLTS

$t_{rr} = 35 \text{ ns}$



**TO-220
CASE 221
STYLE 6**

MARKING DIAGRAM



A = Assembly Location
Y = Year
WW = Work Week
BYV32-200 = Device Code
G = Pb-Free Package
AKA = Diode Polarity

ORDERING INFORMATION

| Device | Package | Shipping |
|------------|---------------------|-----------------|
| BYV32-200G | TO-220 (Pb-Free) | 50 Units / Rail |

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

BYV32-200

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|------------------------------------------------------------------------------------------------------------|---------------------------------|-------------|------------------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V_{RRM} V_{RWM} V_R | 200 | V |
| Average Rectified Forward Current, $T_C = 156^\circ\text{C}$ Per Leg Total Device | $I_{F(AV)}$ | 8.0 16 | A |
| Peak Rectified Forward Current (Square Wave, 20 kHz), $T_C = 154^\circ\text{C}$ – Per Diode Leg | I_{FM} | 16 | A |
| Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz) | I_{FSM} | 100 | A |
| Operating Junction Temperature and Storage Temperature | T_J, T_{stg} | -65 to +175 | $^\circ\text{C}$ |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

| Characteristic | Conditions | Symbol | Value | Unit |
|-------------------------------------------------|------------|-----------------|-------|---------------------------|
| Maximum Thermal Resistance, Junction-to-Case | Min. Pad | $R_{\theta JC}$ | 3.0 | $^\circ\text{C}/\text{W}$ |
| Maximum Thermal Resistance, Junction-to-Ambient | Min. Pad | $R_{\theta JA}$ | 60 | |

ELECTRICAL CHARACTERISTICS

| Characteristic | Symbol | Min | Typical | Max | Unit |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------|--------|--------------|--------------|---------------|
| Instantaneous Forward Voltage (Note 1) ($i_F = 5.0\text{ A}, T_j = 100^\circ\text{C}$) ($i_F = 20\text{ A}, T_j = 25^\circ\text{C}$) | V_F | – – | 0.74 1.01 | 0.85 1.15 | V |
| Instantaneous Reverse Current (Note 1) (Rated dc Voltage, $T_j = 100^\circ\text{C}$) (Rated dc Voltage, $T_j = 25^\circ\text{C}$) | i_R | – – | 21 3.5 | 600 50 | μA |
| Maximum Reverse Recovery Time ($I_F = 1.0\text{ A}, di/dt = 50\text{ A}/\mu\text{s}$) ($I_F = 0.5\text{ A}, I_R = 1.0\text{ A}, I_{REC} = 0.25\text{ A}$) | t_{rr} | – – | – – | 35 25 | ns |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width = 300 s, Duty Cycle $\leq 2.0\%$

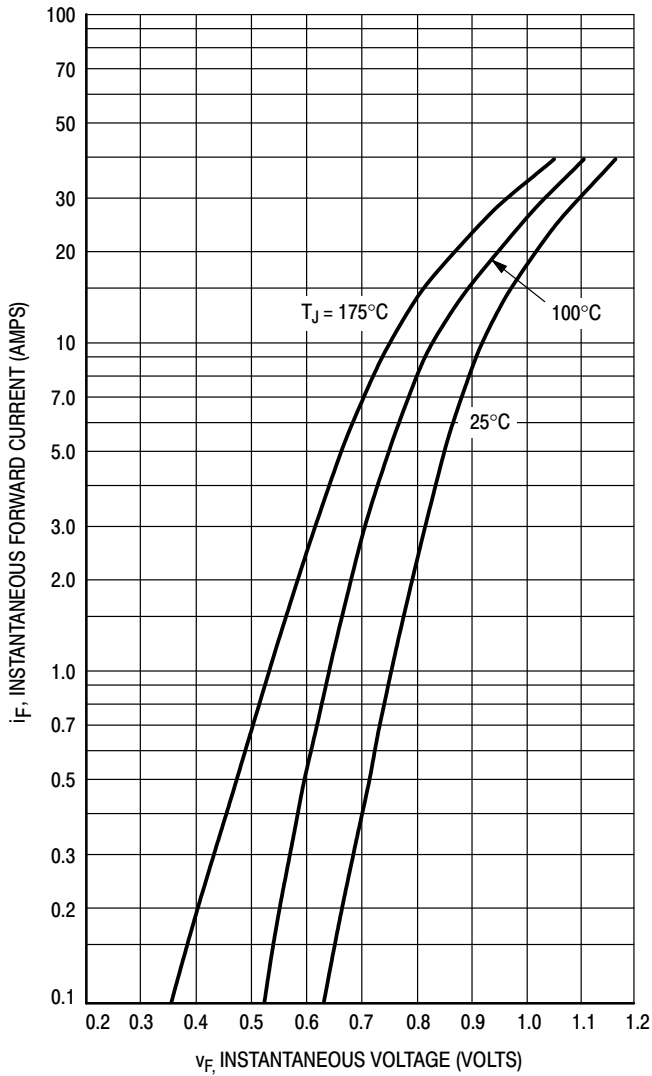


Figure 1. Typical Forward Voltage, Per Leg

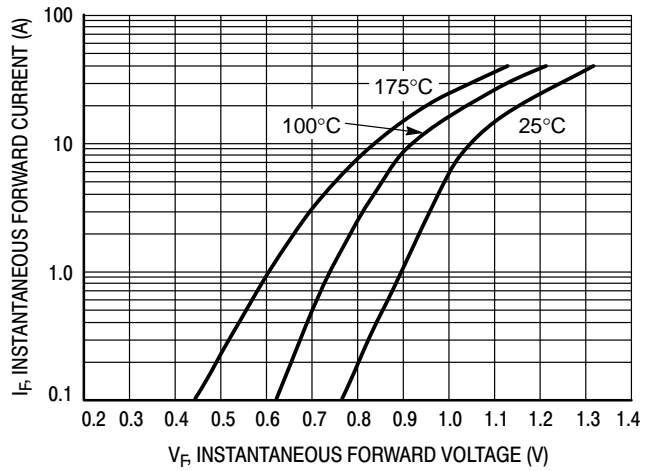


Figure 2. Maximum Forward Voltage

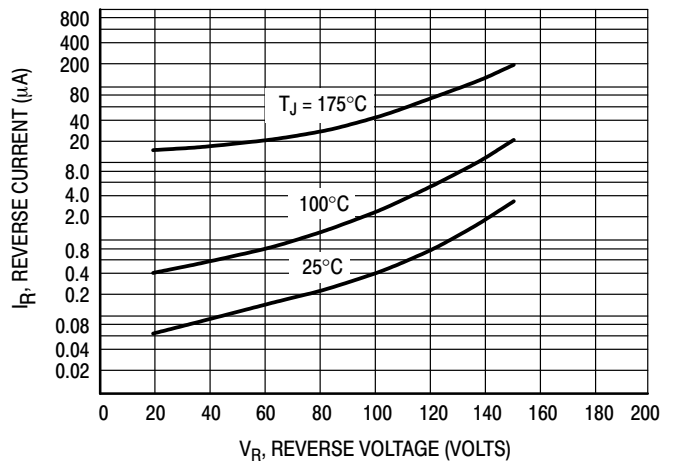


Figure 3. Typical Reverse Current, Per Leg*

* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if V_R is sufficiently below rated V_R .

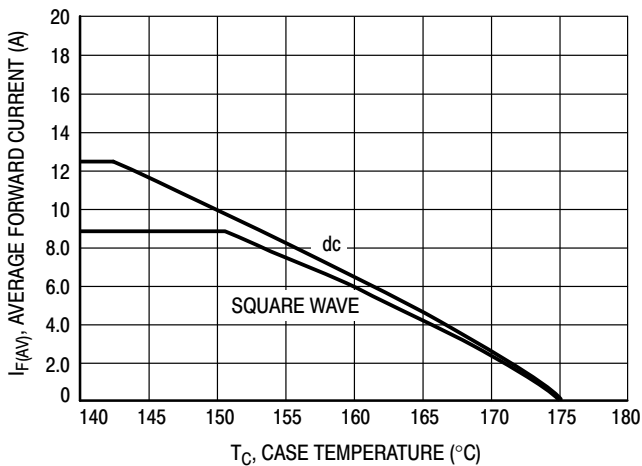


Figure 4. Current Derating, Case, Per Leg

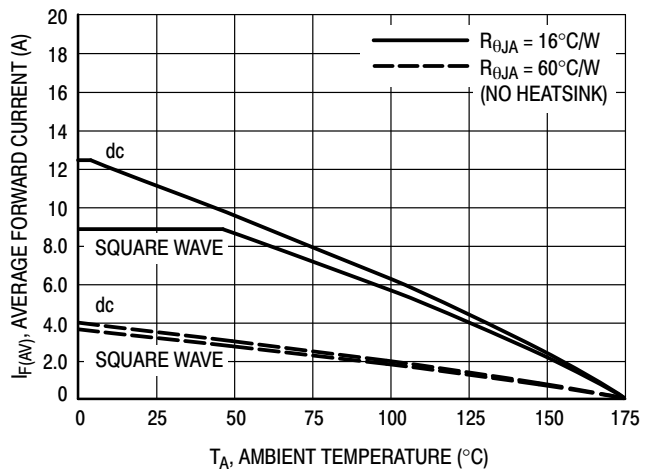


Figure 5. Current Derating, Ambient, Per Leg

BYV32-200

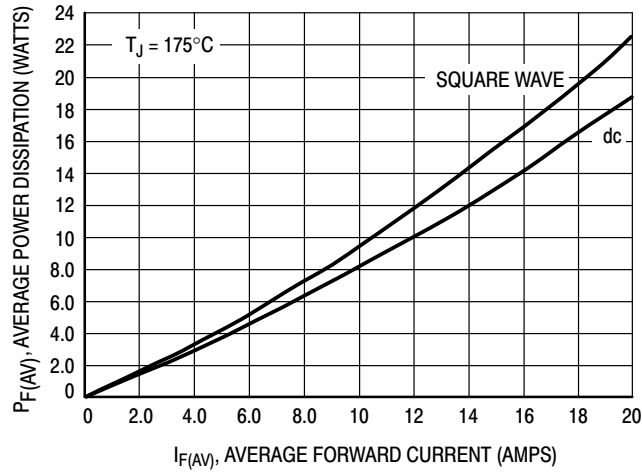


Figure 6. Power Dissipation, Per Leg

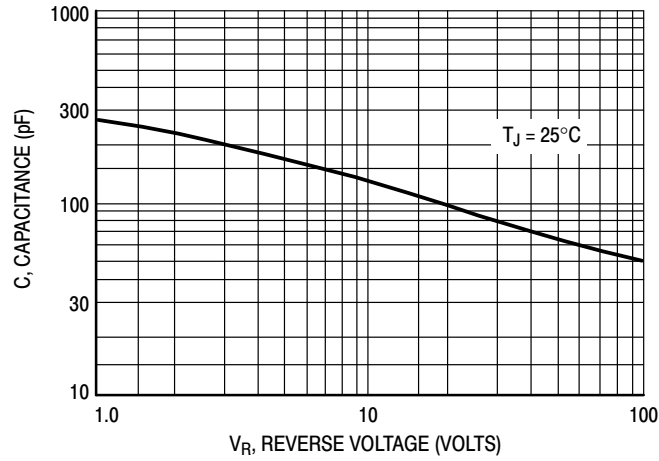


Figure 7. Typical Capacitance, Per Leg

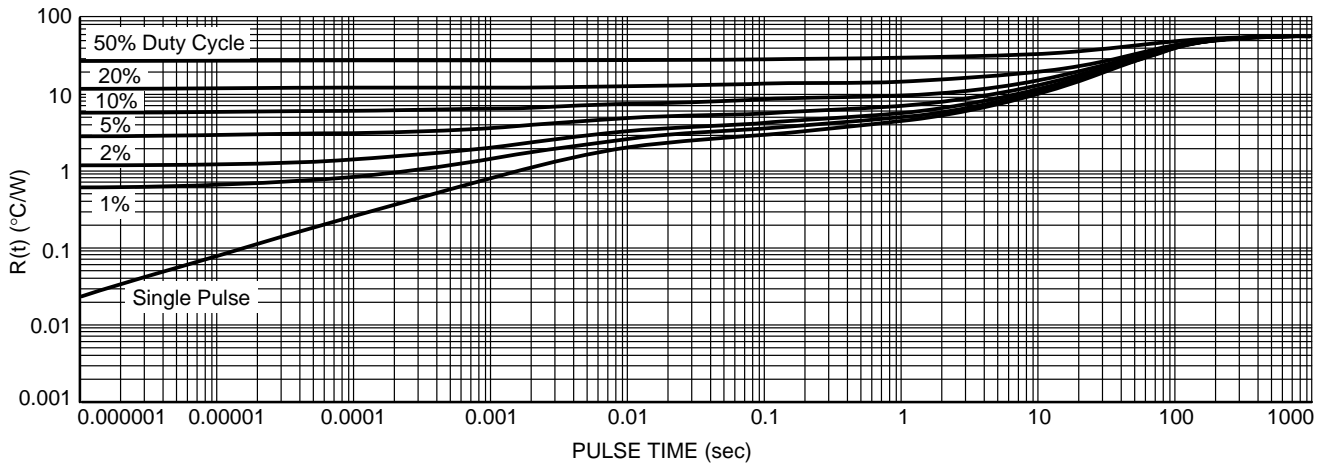


Figure 8. Thermal Response, Junction-to-Ambient

onsemi, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation
onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at www.onsemi.com/support/sales